

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		("thin film transistor" TFT) near6 "P type" near6 ("lightly doped drain" LDD)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:29
S1	123	("thin film transistor" TFT) near6 "P type" near6 ("lightly doped drain" LDD)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:30
S2	11	"349"\$.ccls. and S1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:05
S3	813	"data line" near6 (black or shield)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 10:51
S4	273	"data line" near2 (black or shield)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:49
S5	2761	((349/42) or (349/43)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:51
S6	31	S4 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:52
S7	1296	chung.xa.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:53

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S8	219	"349"\$.ccls. and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 09:53
S9	74	"data line" near6 (overlap\$4 or cover\$4) near6 channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 11:01
S10	34	"349"\$.ccls. and S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 11:02
S11	398	"reflective layer" near6 ("liquid crystal display" LCD)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 10:57
S12	96	349/113 and S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 10:57
S13	68	S12 not @ad>"20030516"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 10:57
S14	8	"reflective layer" near6 (overlap\$4 or cover\$4) near6 channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 11:01
S15	46	(reflect\$4 near6 (film or layer)) near6 (overlap\$4 or cover\$4) near6 channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:04

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S16	9	"349".\$ccls. and S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 11:11
S17	379	(reflect\$4 near6 (film or layer)) near6 (overlap\$4 or cover\$4) near6 (semiconductor or active)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:04
S18	32	"349".\$ccls. and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 11:11
S19	151	(reflect\$4 near6 (film or layer)) near6 (overlap\$4 or cover\$4) near6 (channel or active)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:09
S20	21	"349".\$ccls. and S19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:47
S21	482	reflect\$4 near6 (overlap\$4 or cover\$4) near6 (channel or active)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:46
S22	31	"349".\$ccls. and S21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:46
S23	2	WO-9923530\$.did.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:42

## EAST Search History

S24	293	aluminum near6 (overlap\$4 or cover\$4) near6 (channel or active)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:46
S25	6	"349"\$ .ccls. and S24	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/02/16 13:47